



2DA12130/Y

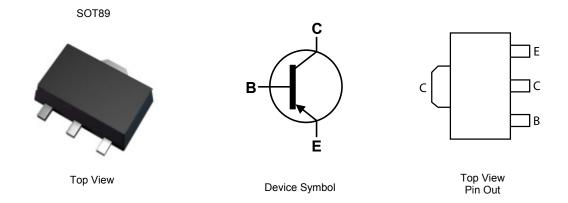
50V PNP POWER SWITCHING TRANSISTOR IN SOT89

Features

- BV_{CEO} > -50V
- I_C = -2A high Continuous Collector Current
- High Gain Holds up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.052 grams (Approximate)



Ordering Information (Notes 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|--------------|---------|--------------------|-----------------|-------------------|
| 2DA1213O-13 | P25X | 13 | 12 | 2,500 |
| 2DA1213Y-13 | P25Y | 13 | 12 | 2,500 |
| 2DA1213Y-13R | P25Y | 13 | 12 | 4,000 |

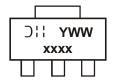
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

Marking Information



xxxx = Product Type Marking Code: P25X = 2DA1213O P25Y = 2DA1213Y YWW = Date Code Marking Y = Last digit of year (ex: 1 = 2011) WW = Week code 01 - 53



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -50 | V |
| Collector-Emitter Voltage | V _{CEO} | -50 | V |
| Emitter-Base Voltage | V _{EBO} | -6 | V |
| Continuous Collector Current | lc | -2 | А |
| Peak Pulse Current | I _{CM} | -2.5 | A |
| Base Current | IB | -500 | mA |

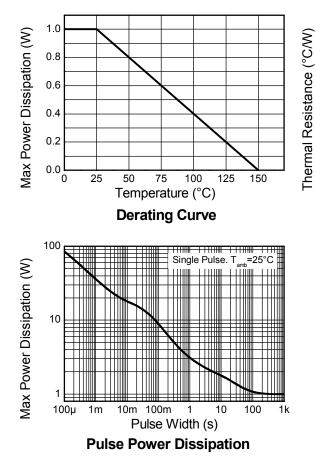
Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

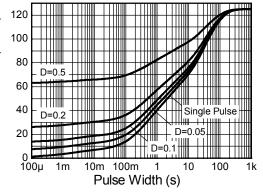
| Characteristic | Symbol | Value | Unit |
|--------------------------------------------------|------------------|-------------|------|
| Power Dissipation (Note 5) | PD | 1 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 125 | °C/W |
| Thermal Resistance, Junction to Leads (Note 6) | R _{θJL} | 18.3 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Notes: 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.

6. Thermal resistance from junction to solder-point (on the exposed collector pad).

Thermal Characteristics and Derating Information







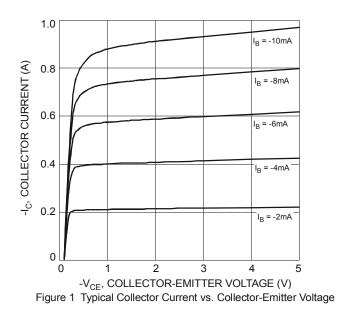


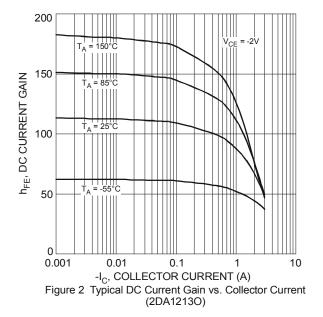
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Min | Тур | Мах | Unit | Test Condition | |
|-----------------------------------------------|--------------------|----------------------|-----|-----|------|------|--------------------------------------------------------------------------------------------|--|
| Collector-Base Breakdown Voltage | | BV _{CBO} | -50 | _ | | V | I _C = -100μA | |
| Collector-Emitter Breakdown Voltage (Note 7) | | BV _{CEO} | -50 | _ | | V | $I_{\rm C}$ = -10mA | |
| Emitter-Base Breakdown Voltage | | BV _{EBO} | -6 | _ | | V | I _E = -100μA | |
| Collector Cut-off Current | | I _{CBO} | — | _ | -100 | nA | $V_{CB} = -50V$ | |
| Emitter Cut-off Current | | I _{EBO} | — | _ | -100 | nA | V _{EB} = -5V | |
| | 2DA1213O | h _{FE} | 70 | | 140 | _ | I _C = -500mA, V _{CE} = -2V | |
| DC Current Gain (Note 8) | 2DA1213Y | | 120 | l — | 240 | | I _C = -500mA, V _{CE} = -2V | |
| | 2DA1213O, 2DA1213Y | | 20 | | | | I _C = -2A, V _{CE} = -2V | |
| Collector-Emitter Saturation Voltage (Note 7) | | V _{CE(sat)} | — | — | -0.5 | V | I _C = -1A, I _B = -50mA | |
| Base-Emitter Turn-On Voltage (Note 7) | | V _{BE(sat)} | — | — | -1.2 | V | I _C = -1A, I _B = -50mA | |
| Transition Frequency | | f _T | — | 160 | — | MHz | I _C = -100mA, V _{CE} = -2V, f = 100MHz | |
| Output Capacitance | | C _{obo} | — | 17 | | pF | VCB = -10V, IE = 0, f = 1MHz | |
| Turn-On Time | | t _{on} | _ | 25 | | ns | $y_{1} = 0y_{1} + - 40$ | |
| Storage Time | | t _(s) | _ | 130 | | ns | V _{CE} = -2V, I _C = -1A, I _{B1} = -I _{B2} = -50mA | |
| Fall Time | | t _(f) | _ | 12 | _ | ns | 1B11B230/11A | |

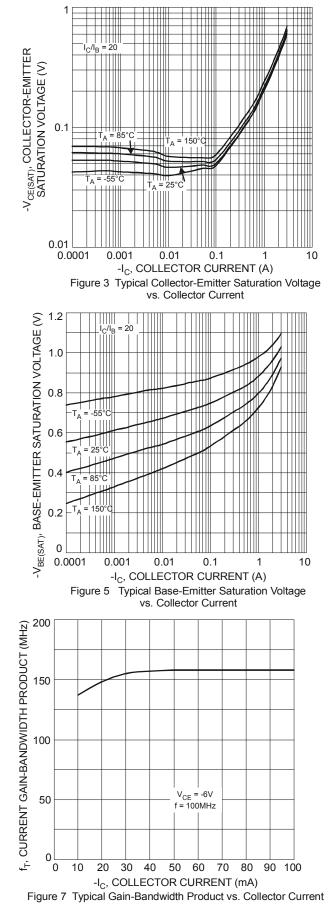
Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

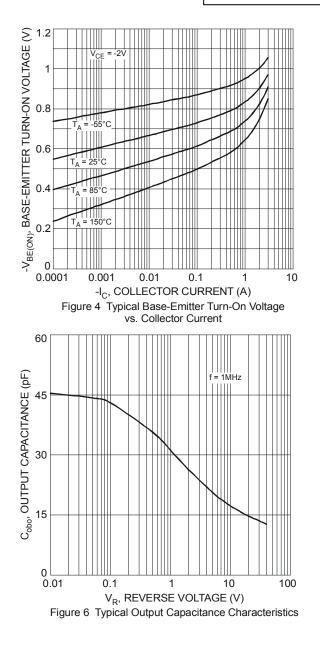
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







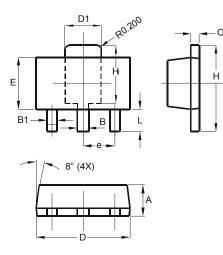






Package Outline Dimensions

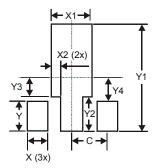
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT89 | | | | |
|-------|----------------------|------|--|--|
| Dim | Min Max | | | |
| Α | 1.40 | 1.60 | | |
| В | 0.44 | 0.62 | | |
| B1 | 0.35 | 0.54 | | |
| С | 0.35 | 0.44 | | |
| D | 4.40 | 4.60 | | |
| D1 | 1.62 | 1.83 | | |
| ш | 2.29 | 2.60 | | |
| е | 1.50 Typ | | | |
| Н | 3.94 | 4.25 | | |
| H1 | 2.63 | 2.93 | | |
| L | 0.89 | 1.20 | | |
| All [| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Х | 0.900 |
| X1 | 1.733 |
| X2 | 0.416 |
| Y | 1.300 |
| Y1 | 4.600 |
| Y2 | 1.475 |
| Y3 | 0.950 |
| Y4 | 1.125 |
| C | 1.500 |



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